

S/N Unknown

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Behnam Moradi et al. Examiner: Unknown
Serial No.: Unknown Group Art Unit: Unknown
Filed: Herewith Docket: 303.591US2
Title: STRUCTURE AND METHOD TO ENHANCE FIELD EMISSION IN FIELD
EMITTER DEVICE

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

In compliance with the duty imposed by 37 C.F.R. § 1.56, and in accordance with 37 C.F.R. §§ 1.97 *et. seq.*, the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified patent application. Applicants respectfully request that this Information Disclosure Statement be entered and the documents listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to the provisions of MPEP 609, Applicants request that a copy of the 1449 form, initialed as being considered by the Examiner, be returned to the Applicants with the next official communication.

Pursuant to 37 C.F.R. §1.98(d), copies of the listed documents are not provided, except for U.S. Pat. 6,323,075, as these documents, except for U.S. Pat. 6,323,075, were previously cited by or submitted to the U.S. Patent Office in connection with Applicants' prior U.S. application, Serial No. 09/483409, filed on January 14, 2000, which is relied upon for an earlier filing date under 35 U.S.C. §120.

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Dkt: 303.591US2

The Examiner is invited to contact the Applicants' Representative at the below-listed telephone number if there are any questions regarding this communication.

Respectfully submitted,

BEHNAM MORADI ET AL.

By their Representatives,

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Date 20 Nov '03

By 
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"Express Mail" mailing label number: EV298566107US

Date of Deposit: November 20, 2003

This paper or fee is being deposited on the date indicated above with the United States Postal Service pursuant to 37 CFR 1.10, and is addressed to The Commissioner for Patents, Mail Stop Patent Application, P.O. Box 1450, Alexandria, VA 22313-1450.

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COMMUNICATION CONCERNING RELATED APPLICATION(S)

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

<u>Serial/Patent No.</u>	<u>Filing Date</u>	<u>Attorney Docket</u>	<u>Title</u>
09/144207 6232705	September 1, 1998	303.504US1	STRUCTURE AND METHOD FOR IMPROVED FIELD EMITTER ARRAYS
09/695632 6495955	October 24, 2000	303.504US2	STRUCTURE AND METHOD FOR IMPROVED FIELD EMITTER ARRAYS
10/054601	January 22, 2002	303.504US3	STRUCTURE AND METHOD FOR IMPROVED FIELD EMITTER ARRAYS
09/261477 6417016	February 26, 1999	303.562US1	STRUCTURE AND METHOD FOR FIELD EMITTER TIPS

COMMUNICATION CONCERNING CO-PENDING APPLICATIONS

Serial Number: Unknown

Filing Date: Herewith

Title: STRUCTURE AND METHOD TO ENHANCE FIELD EMISSION IN FIELD EMITTER DEVICE

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10/193016

July 9, 2002

303.562US2

**STRUCTURE AND METHOD FOR
FIELD EMITTER TIPS**

Respectfully submitted,

BEHNAM MORADI ET AL.

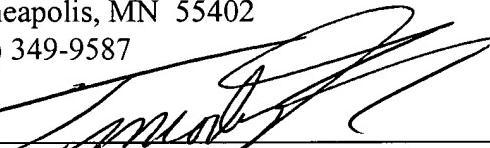
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Substitute for form 1449A/PTO													
INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>													
<table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td colspan="2" style="padding: 2px; text-align: center;"><i>Complete if Known</i></td> </tr> <tr> <td style="width: 50%; padding: 2px;">Application Number</td> <td style="width: 50%; padding: 2px;">Unknown</td> </tr> <tr> <td style="padding: 2px;">Filing Date</td> <td style="padding: 2px;">Even Date Herewith</td> </tr> <tr> <td style="padding: 2px;">First Named Inventor</td> <td style="padding: 2px;">Moradi, Behnam</td> </tr> <tr> <td style="padding: 2px;">Group Art Unit</td> <td style="padding: 2px;">Unknown</td> </tr> <tr> <td style="padding: 2px;">Examiner Name</td> <td style="padding: 2px;">Ramsey, Kenneth</td> </tr> </table>		<i>Complete if Known</i>		Application Number	Unknown	Filing Date	Even Date Herewith	First Named Inventor	Moradi, Behnam	Group Art Unit	Unknown	Examiner Name	Ramsey, Kenneth
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Examiner Name	Ramsey, Kenneth												
Sheet 1 of 2													
Attorney Docket No: 303.591US2													

US PATENT DOCUMENTS						
Examiner Initial *	USP Document Number	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	Filing Date If Appropriate
	US-3,665,241	05/23/1972	Spindt, C. A., et al.	313	351	07/13/1970
	US-3,755,704	08/28/1973	Spindt, Charles A., et al.	313	309	02/06/1970
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Examiner Initials*	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	T ²

EXAMINER

DATE CONSIDERED

Substitute Disclosure Statement Form (PTO-1449)

* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. 1 Applicant's unique citation designation number (optional) 2 Applicant is to place a check mark here if English language Translation is attached

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Sheet 2 of 2		Attorney Docket No: 303.591US2											

OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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EXAMINER

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